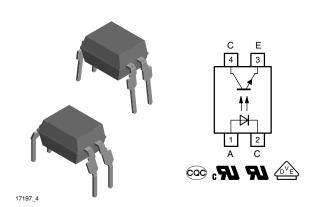


## **Optocoupler, Phototransistor Output, High Temperature**



#### LINKS TO ADDITIONAL RESOURCES



#### **DESCRIPTION**

The TCET110. consists of a phototransistor optically coupled to a gallium arsenide infrared-emitting diode in a 4-lead plastic dual inline package.

#### **AGENCY APPROVALS**

- UL 1577
- cUL 1577
- DIN EN 60747-5-5 (VDE 0884-5)
- BSI: EN 62368-1:2014
- CQC GB4943.1-2011
- CQC GB8898-2011

#### **FEATURES**

- High common mode rejection
- · Low temperature coefficient of CTR
- CTR offered in 7 groups
- Reinforced isolation provides circuit protection against electrical shock (safety class II)



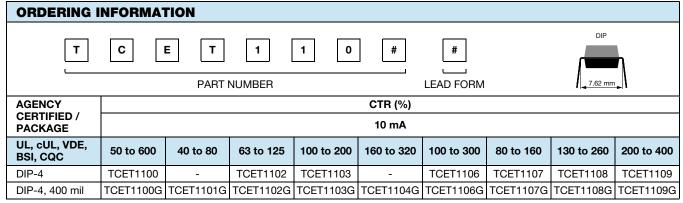
RoHS

- Isolation materials according to UL 94 V-0
- Pollution degree 2 (DIN / VDE 0110 / resp. IEC 60664)
- Climatic classification 55 / 100 / 21 (IEC 60068 part 1)
- Rated impulse voltage (transient overvoltage)  $V_{IOTM} = 6 \text{ kV}_{peak}$
- Isolation test voltage (partial discharge test voltage)  $V_{pd} = 1.6 \; kV$
- Rated isolation voltage (RMS includes DC)
   V<sub>IOWM</sub> = 600 V<sub>RMS</sub>
- Rated recurring peak voltage (repetitive)
   V<sub>IORM</sub> = 848 V<sub>peak</sub>
- Creepage current resistance according to VDE 0303 / IEC 60112 comparative tracking index: CTI ≥ 175
- Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912"><u>www.vishay.com/doc?99912</u></a>

#### **APPLICATIONS**

Circuits for safe protective separation against electrical shock according to safety class II (reinforced isolation):

- For application class I to IV at mains voltage ≤ 300 V
- For application class I to III at mains voltage ≤ 600 V according to DIN EN 60747-5-5 (VDE 0884), suitable for:
  - Switch-mode power supplies
  - Line receiver
  - Computer peripheral interface
  - Microprocessor system interface



#### Note

G = lead form 10.16 mm; G is not marked on the body

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ABSOLUTE MAXIMUM RATINGS (T <sub>amb</sub> = 25 °C, unless otherwise specified)								
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT				
INPUT								
Reverse voltage		$V_{R}$	6	V				
Forward current		I <sub>F</sub>	60	mA				
Forward surge current	t <sub>p</sub> ≤ 10 μs	I <sub>FSM</sub>	1.5	Α				
ОUТРUТ								
Collector emitter voltage		V <sub>CEO</sub>	70	V				
Emitter collector voltage		V <sub>ECO</sub>	7	V				
Collector current		I <sub>C</sub>	50	mA				
Collector peak current	$t_p/T = 0.5, t_p \le 10 \text{ ms}$	I <sub>CM</sub>	100	mA				
COUPLER								
Isolation test voltage (RMS)	t = 1 min	V <sub>ISO</sub>	5000	$V_{RMS}$				
Operating ambient temperature range		T <sub>amb</sub>	-40 to +100	°C				
Storage temperature range		T <sub>stg</sub>	-55 to +125	°C				
Soldering temperature (1)	2 mm from case, ≤ 10 s	T <sub>sld</sub>	260	°C				

#### **Notes**

- Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not
  implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute
  maximum ratings for extended periods of the time can adversely affect reliability
- (1) Refer to wave profile for soldering conditions for through hole devices

THERMAL CHARACTERISTICS			
PARAMETER	SYMBOL	VALUE	UNIT
LED power dissipation	P <sub>diss</sub>	100	mW
Output power dissipation	P <sub>diss</sub>	150	mW
Maximum LED junction temperature	T <sub>jmax.</sub>	125	°C
Maximum output die junction temperature	T <sub>jmax.</sub>	125	°C
Thermal resistance, junction emitter to board	$\theta_{EB}$	173	°C/W
Thermal resistance, junction emitter to case	$\theta_{\sf EC}$	149	°C/W
Thermal resistance, junction detector to board	$\theta_{DB}$	111	°C/W
Thermal resistance, junction detector to case	$\theta_{DC}$	127	°C/W
Thermal resistance, junction emitter to junction detector	$\theta_{ED}$	173	°C/W
Thermal resistance, board to ambient (1)	$\theta_{BA}$	197	°C/W
Thermal resistance, case to ambient (1)	$\theta_{CA}$	4041	°C/W

#### Notes

- The thermal model is represented in the thermal network below. Each resistance value given in this model can be used to calculate the
  temperatures at each node for a given operating condition. The thermal resistance from board to ambient will be dependent on the type of
  PCB, layout and thickness of copper traces. For a detailed explanation of the thermal model, please reference Vishay's "Thermal
  Characteristics of Optocouplers" application note
- (1) For 2 layer FR4 board (4" x 3" x 0.062")



<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)								
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT		
INPUT								
Forward voltage	$I_F = 50 \text{ mA}$	$V_{F}$	-	1.25	1.6	V		
Junction capacitance	$V_R = 0$ , $f = 1 MHz$	C <sub>j</sub>	-	50	-	pF		
OUTPUT	OUTPUT							
Collector emitter voltage	$I_C = 1 \text{ mA}$	$V_{CEO}$	70	-	-	V		
Emitter collector voltage	$I_E = 100  \mu A$	V <sub>ECO</sub>	7	ı	-	V		
Collector emitter cut-off current	$V_{CE} = 20 \text{ V}, I_F = 0 \text{ A}, E = 0$	I <sub>CEO</sub>	ı	10	100	nA		
COUPLER								
Collector emitter saturation voltage	$I_F = 10 \text{ mA}, I_C = 1 \text{ mA}$	V <sub>CEsat</sub>	-	-	0.3	V		
Cut-off frequency	$V_{CE}$ = 5 V, $I_F$ = 10 mA, $R_L$ = 100 $\Omega$	f <sub>c</sub>	-	110	-	kHz		
Coupling capacitance	f = 1 MHz	C <sub>k</sub>	-	0.3	-	pF		

#### Note

 Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements

CURRENT TRANSFER RATIO									
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT		
		TCET1101G	CTR	13	30	-	%		
	V - 5 V I - 1 mA	TCET1102, TCET1102G	TCET1102G	22	45	-	%		
	$V_{CE} = 5 \text{ V}, I_{F} = 1 \text{ mA}$	TCET1103, TCET1103G	CTR	34	70	-	%		
		TCET1104G	CTR	56	90	-	%		
		TCET1100, TCET1100G	CTR	50	-	600	%		
		TCET1106, TCET1106G	CTR	100	-	300	%		
I <sub>C</sub> /I <sub>F</sub>	$V_{CE} = 5 \text{ V}, I_F = 5 \text{ mA}$	TCET1107, TCET1107G	CTR	80	-	160	%		
·O ·F		TCET1108, TCET1108G	CTR	130	-	260	%		
		TCET1109, TCET1109G	CTR	200	-	400	%		
		TCET1101, TCET1101G	CTR	40	-	80	%		
$V_{CE} = 5 V, I_{F}$	V - 5 V I - 10 1	TCET1102, TCET1102G	CTR	63	-	125	%		
	VCE = 5 V, IF = 10 IIIA	TCET1103, TCET1103G	CTR	100	-	200	%		
		TCET1104, TCET1104G	CTR	160	-	320	%		

MAXIMUM SAFETY RATINGS								
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT		
INPUT								
Forward current		I <sub>F</sub>	-	-	130	mA		
OUTPUT								
Power dissipation		P <sub>diss</sub>	ı	-	265	mW		
COUPLER	COUPLER							
Rated impulse voltage		V <sub>IOTM</sub>	=	-	6	kV		
Safety temperature		T <sub>si</sub>	ı	-	150	°C		

#### Note

According to DIN EN 60747-5-5 (see figure 2). This optocoupler is suitable for safe electrical isolation only within the safety ratings.
 Compliance with the safety ratings shall be ensured by means of suitable protective circuits

INSULATION RATED PARAMETERS							
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT	
Partial discharge test voltage - routine test	100 %, t <sub>test</sub> = 1 s	V <sub>pd</sub>	1.6	-	-	kV	
Partial discharge test voltage -	$t_{Tr} = 60 \text{ s}, t_{test} = 10 \text{ s},$	V <sub>IOTM</sub>	6	-	-	kV	
lot test (sample test)	(see figure 2)	$V_{pd}$	1.3	-	-	kV	
	V <sub>IO</sub> = 500 V	R <sub>IO</sub>	10 <sup>12</sup>	-	-	Ω	
Insulation resistance	V <sub>IO</sub> = 500 V, T <sub>amb</sub> = 100 °C	R <sub>IO</sub>	10 <sup>11</sup>	-	-	Ω	
insulation resistance	V <sub>IO</sub> = 500 V, T <sub>amb</sub> = 150 °C (construction test only)	R <sub>IO</sub>	10 <sup>9</sup>	-	-	Ω	

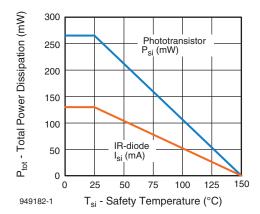


Fig. 1 - Derating Diagram

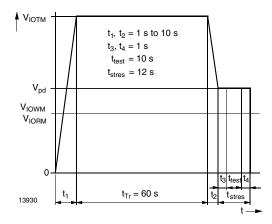


Fig. 2 - Test Pulse Diagram for Sample Test According to DIN EN 60747-5-5 / DIN EN 60747-; IEC 60747

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SWITCHING CHARACTERISTICS							
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT	
Delay time	$V_S$ = 5 V, $I_C$ = 2 mA, $R_L$ = 100 $\Omega$ , (see Fig. 3)	t <sub>d</sub>	-	3	-	μs	
Rise time	$V_S$ = 5 V, $I_C$ = 2 mA, $R_L$ = 100 $\Omega$ , (see Fig. 3)	t <sub>r</sub>	-	3	-	μs	
Turn-on time	$V_S$ = 5 V, $I_C$ = 2 mA, $R_L$ = 100 $\Omega$ , (see Fig. 3)	t <sub>on</sub>	-	6	-	μs	
Storage time	$V_S$ = 5 V, $I_C$ = 2 mA, $R_L$ = 100 $\Omega$ , (see Fig. 3)	t <sub>s</sub>	-	0.3	-	μs	
Fall time	$V_S$ = 5 V, $I_C$ = 2 mA, $R_L$ = 100 $\Omega$ , (see Fig. 3)	t <sub>f</sub>	-	4.7	-	μs	
Turn-off time	$V_S$ = 5 V, $I_C$ = 2 mA, $R_L$ = 100 $\Omega$ , (see Fig. 3)	t <sub>off</sub>	-	5	-	μs	
Turn-on time	$V_S$ = 5 V, $I_F$ = 10 mA, $R_L$ = 1 k $\Omega$ , (see Fig. 4)	t <sub>on</sub>	-	9	-	μs	
Turn-off time	$V_S = 5 \text{ V}, I_F = 10 \text{ mA}, R_L = 1 \text{ k}\Omega,$ (see Fig. 4)	t <sub>off</sub>	-	10	-	μs	

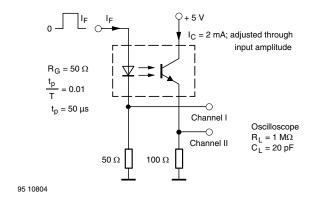


Fig. 3 - Test Circuit, Non-Saturated Operation

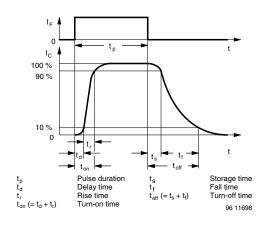


Fig. 5 - Switching Times

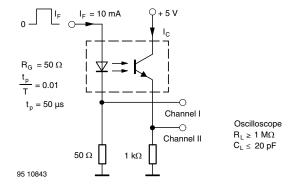


Fig. 4 - Test Circuit, Saturated Operation

### TYPICAL CHARACTERISTICS (T<sub>amb</sub> = 25 °C, unless otherwise specified)

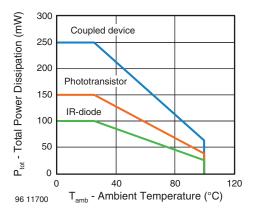
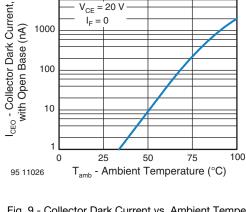


Fig. 6 - Total Power Dissipation vs. Ambient Temperature



10 000

Fig. 9 - Collector Dark Current vs. Ambient Temperature

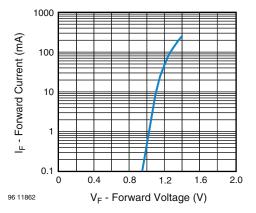


Fig. 7 - Forward Current vs. Forward Voltage

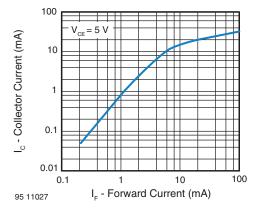


Fig. 10 - Collector Current vs. Forward Current

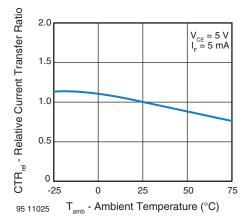


Fig. 8 - Relative Current Transfer Ratio vs. **Ambient Temperature** 

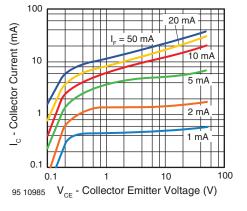


Fig. 11 - Collector Current vs. Collector Emitter Voltage

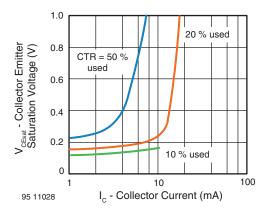


Fig. 12 - Collector Emitter Saturation Voltage vs. Collector Current

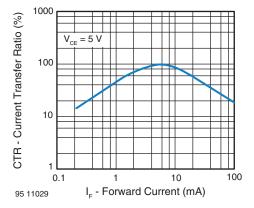


Fig. 13 - Current Transfer Ratio vs. Forward Current

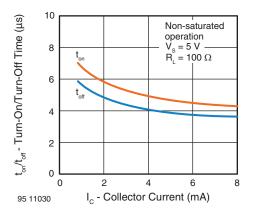


Fig. 14 - Turn-On / Off Time vs. Collector Current

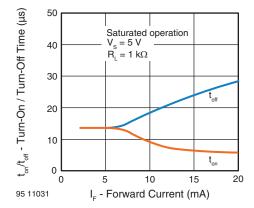
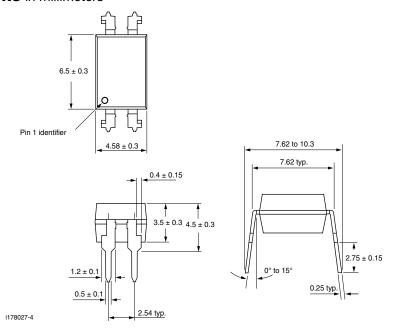
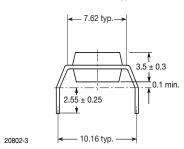


Fig. 15 - Turn-On / Off Time vs. Forward Current

#### **PACKAGE DIMENSIONS** in millimeters



#### TCET1100G type



#### **PACKAGE MARKING**





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